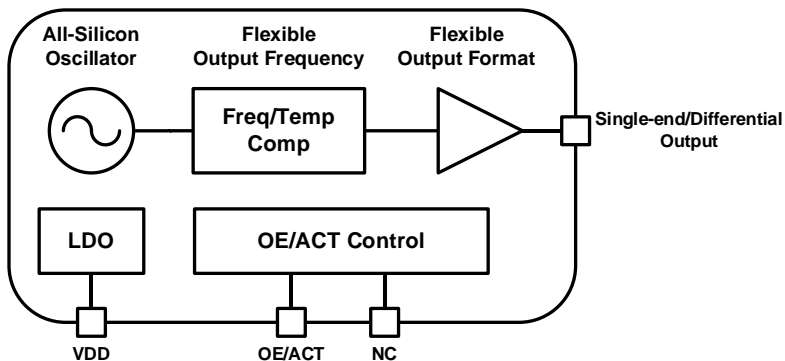


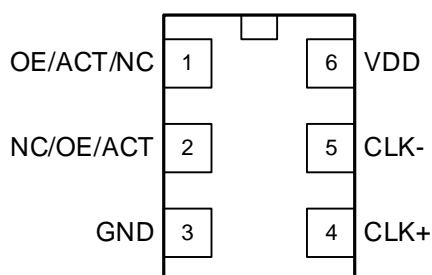
## AS5001 Arcadium™ Low Jitter Fixed Frequency Oscillator, 10 kHz to 350 MHz

The AS5001 Arcadium™ all-silicon oscillator utilizes proprietary frequency synthesis and sensor technologies to provide a quartz-free, MEMS-free, low jitter clock at any output frequency. The device is factory-programmed to output frequencies ranging from 10 kHz to 350 MHz with <math><0.026</math> ppb resolution and maintains low jitter across its operating range. The AS5001 uses on-chip temperature and strain sensors, and an advanced LC tank architecture to achieve excellent reliabilities even in high impact shock scenarios.

AS5001's on-chip power supply filtering provides industry-leading power supply noise rejection, simplifying the task of generating low jitter clocks in noisy systems that use switched-mode power supplies. Offered in a variety of industry-standard packages, the AS5001 has a dramatically simplified supply chain that enables Aeonsemi to ship samples shortly after receipt of order. The AS5001 is factory-configurable for a wide variety of user specifications, including frequency, output format, and OE pin assignment. Specific configurations are factory programmed at time of shipment, eliminating the long lead times associated with custom oscillators. This process also guarantees 100% electrical testing of every device before shipment.



Pin Assignments



Top view

5032 and 3225 package



### KEY FEATURES

- Quartz-free and MEMS-free without mechanical moving parts
- Flexible output frequency and format; user selectable
- Differential: 10 kHz to 350 MHz
- CMOS: 10 kHz to 212.5 MHz
- LVPECL, LVDS, CML, HCSL, CMOS, or Dual CMOS output options
- Low jitter: 350 fs Typ RMS (12 kHz – 20 MHz)
- Compliant to PCIe Gen 1/2/3/4/5/6 jitter requirements
- Temperature stability:
  - $\pm 12$  ppm (0 to 70 °C)
  - $\pm 20$  ppm (-20 to 85 °C)
  - $\pm 35$  ppm (-40 to 85 °C)
  - $\pm 35$  ppm (-40 to 105 °C)
- Integrated LDO for on-chip power supply noise filtering
- Support 1.8V, 2.5V, 3.3V  $V_{DD}$  power supply operation
- Industrial standard 3225 and 5032 package footprints

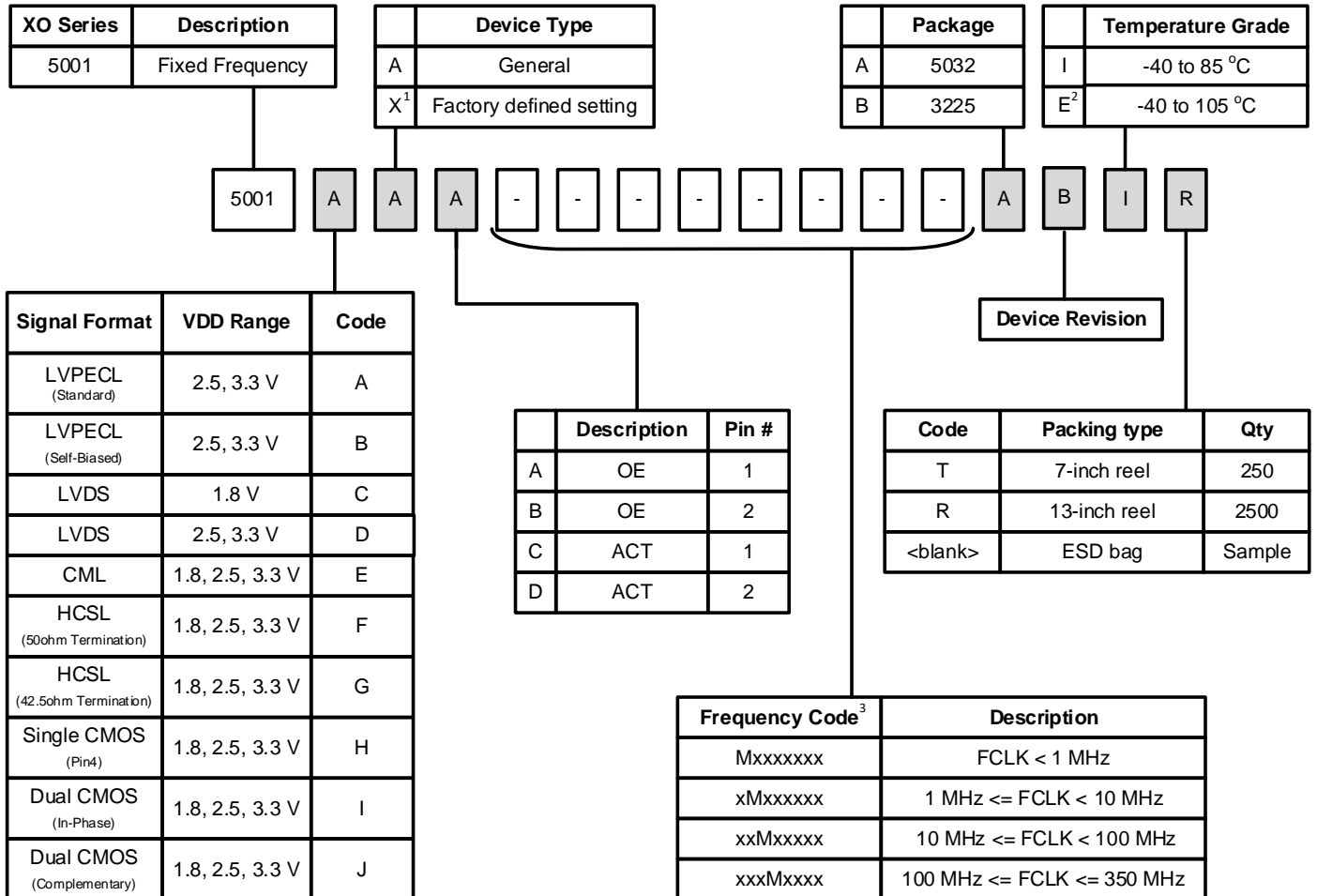
### APPLICATIONS

- 1G/10G/40G/100G/200G Ethernet
- Servers, switches, storage, NICs, search acceleration
- Test and measurement
- Clock and data recovery
- FPGA/ASIC clocking

Pin #	Descriptions
1, 2	Selectable via ordering option OE = Output Enable. Active High ACT = Device Active. Active High NC = No connect
3	GND = Ground
4	CLK+ = Clock output
5	CLK- = Complementary clock output
6	VDD = Power supply

## 1. Ordering Guide

The AS5001 Oscillator supports a variety of options including frequency, output format, and OE/ACT pin location, as shown in the chart below. Specific device configurations are programmed into the part at time of shipment, and samples are available in 2 weeks.



### Notes:

1. "X" refers to the ID for the unique configuration with factory-defined settings, the value ranges from "B" to "Z".
2. Contact [aeonsemi.com/contact\\_us](http://aeonsemi.com/contact_us) for advanced -40~105°C option.
3. For example: 156.25 MHz = 156M2500; 25 MHz = 25M00000.

## 2. Electrical Specifications

**Table 2.1. Electrical Specifications**
 $V_{DD} = 1.8\text{ V}, 2.5\text{ or }3.3\text{ V} \pm 5\%$ ,  $T_A = -40\text{ to }105\text{ }^\circ\text{C}$ 

Parameter	Symbol	Test Condition/Comment	Min	Typ	Max	Unit
Temperature Range	$T_A$		-40	—	105	$^\circ\text{C}$
Frequency Range	$F_{CLK}$	LVPECL, LVDS, CML, HCSL	0.01	—	350	MHz
		CMOS	0.01	—	212.5	MHz
Supply Voltage	$V_{DD}$		1.71	—	3.47	V
Supply Current ( $F_{CLK} = 50\text{ MHz}$ )	$I_{DD}$	Tristate Hi-Z ( $OE = 0$ )	—	40	50	mA
		Ready State ( $ACT = 0$ )	—	1	2	mA
		LVPECL (Standard)	—	70	80	mA
		LVPECL (Self-Biased)	—	60	70	mA
		LVDS	—	45	55	mA
		HCSL	—	60	70	mA
		CML	—	60	70	mA
		Single CMOS	—	40	55	mA
		Dual CMOS	—	50	60	mA
Temperature Stability <sup>1</sup>	$F_{STAB}$	0 to $+70^\circ\text{C}$	-12	—	+12	ppm
		-20 to $+85^\circ\text{C}$	-20	—	+20	ppm
		-40 to $+85^\circ\text{C}$	-35	—	+35	ppm
		-40 to $+105^\circ\text{C}^3$	-35	—	+35	ppm
Frequency offset <sup>2</sup>	$F_{OFFSET}$	0 to $+70^\circ\text{C}$	-23	—	+18	ppm
		-20 to $+85^\circ\text{C}$	-21	—	+18	ppm
		-40 to $+85^\circ\text{C}$	-20	—	+20	ppm
		-40 to $+105^\circ\text{C}^3$	-22	—	+20	ppm
Rise/Fall Time (20% to 80% $V_{PP}$ )	$T_R/T_F$	LVPECL / LVDS / CML	—	—	350	ps
		CMOS ( $C_L = 5\text{ pF}$ )	—	0.5	1.5	ns
		HCSL, $F_{CLK} > 50\text{ MHz}$	—	—	550	ps
Duty Cycle	DC	All formats	45	—	55	%
Output Enable (OE) <sup>4</sup>	$V_{IH}$	—	$0.7 \times V_{DD}$	—	—	V
	$V_{IL}$	—	—	—	$0.3 \times V_{DD}$	V
	$T_D$	Output Disable Time, $F_{CLK} > 10\text{ MHz}$	—	—	3	$\mu\text{s}$
	$T_E$	Output Enable Time, $F_{CLK} > 10\text{ MHz}$	—	—	20	$\mu\text{s}$
Output Enable (ACT) <sup>4</sup>	$V_{IH}$	—	$0.7 \times V_{DD}$	—	—	V
	$V_{IL}$	—	—	—	$0.3 \times V_{DD}$	V
	$T_D$	Output Disable Time, $F_{CLK} > 10\text{ MHz}$	—	—	3	$\mu\text{s}$
	$T_S$	Device standby time, $F_{CLK} > 10\text{ MHz}$	—	—	40	$\mu\text{s}$
	$T_E$	Output Enable Time, $F_{CLK} > 10\text{ MHz}$	—	—	400	$\mu\text{s}$
Powerup Time	$T_{OSC}$	Time from $0.9 \times V_{DD}$ until output frequency ( $F_{CLK}$ ) within spec	—	—	4	ms

Parameter	Symbol	Test Condition/Comment	Min	Typ	Max	Unit
LVPECL Output Option <sup>5</sup> (Standard)	V <sub>OC</sub>	Mid-level	V <sub>DD</sub> -1.55	V <sub>DD</sub> -1.4	V <sub>DD</sub> -1.25	V
	V <sub>O</sub>	Swing (diff)	1.35	1.6	1.85	V <sub>PP</sub>
LVPECL Output Option <sup>5</sup> (Self-Biased)	V <sub>O</sub>	Swing (diff)	1.35	1.6	1.85	V <sub>PP</sub>
LVDS Output Option <sup>6</sup>	V <sub>OC</sub>	Mid-level (2.5 V, 3.3 V V <sub>DD</sub> )	1.125	1.20	1.275	V
		Mid-level (1.8 V V <sub>DD</sub> )	0.78	0.85	0.92	V
	V <sub>O</sub>	Swing (diff)	0.64	0.8	0.96	V <sub>PP</sub>
HCSL Output Option <sup>7</sup> (R <sub>term</sub> = 50 Ω)	V <sub>OC</sub>	Mid-level	0.35	0.4	0.45	V
	V <sub>O</sub>	Swing (diff)	1.28	1.6	1.92	V <sub>PP</sub>
HCSL Output Option <sup>7</sup> (R <sub>term</sub> = 42.5 Ω)	V <sub>OC</sub>	Mid-level	0.35	0.4	0.45	V
	V <sub>O</sub>	Swing (diff)	1.29	1.62	1.94	V <sub>PP</sub>
CML Output Option	V <sub>OC</sub>	Mid-level	V <sub>DD</sub> -0.35	V <sub>DD</sub> -0.4	V <sub>DD</sub> -0.45	V
	V <sub>O</sub>	Swing (diff)	1.28	1.6	1.92	V <sub>PP</sub>
CMOS Output Option	V <sub>OH</sub>	I <sub>OH</sub> = 8/6/4 mA for 3.3/2.5/1.8V V <sub>DD</sub>	0.83×V <sub>DD</sub>	—	—	V
	V <sub>OL</sub>	I <sub>OL</sub> = 8/6/4 mA for 3.3/2.5/1.8V V <sub>DD</sub>	—	—	0.17×V <sub>DD</sub>	V

**Notes:**

1. Frequency / temperature characteristics with offset removed.
2. Inclusive of initial frequency tolerance at 25°C, 10-year aging at 25°C, and variations over supply voltage, load and humidity after soldering-reflow shift settles.
3. Contact [aeonsemi.com/contact\\_us](http://aeonsemi.com/contact_us) for advanced -40~105°C option.
4. OE/ACT includes a 50 kΩ pull-up to V<sub>DD</sub> for OE/ACT active high. NC (No Connect) pin includes a 50 kΩ pull-down to GND.
5. R<sub>term</sub> = 50 Ω to V<sub>DD</sub> - 2.0 V (see Figure 4.1. )
6. R<sub>term</sub> = 100 Ω (differential) (see Figure 4.2. )
7. R<sub>term</sub> = 50/42.5 Ω to GND (see Figure 4.4. )

Table 2.2. Clock Output Phase Jitter and PSRR

V<sub>DD</sub> = 1.8 V, 2.5 or 3.3 V ± 5%, T<sub>A</sub> = -40 to 105 °C

Parameter	Symbol	Test Condition/Comment	Min	Typ	Max	Unit
Phase Jitter (RMS, 12 kHz - 20 MHz) <sup>1,2</sup> F <sub>CLK</sub> ≥ 10 MHz	φ <sub>J</sub>	Differential Formats	—	350	750	fs
		CMOS, Dual CMOS	—	350	—	fs
Phase Jitter (RMS, 50 kHz - 20 MHz) F <sub>CLK</sub> ≥ 100 MHz	φ <sub>J</sub>	Differential Formats	—	150	250	fs
		CMOS, Dual CMOS	—	100	—	fs
Spurs Induced by External Power Supply Noise 50 mV <sub>PP</sub> Ripple LVDS 156.25 MHz Output V <sub>DD</sub> = 1.8 V	PSRR	100 kHz sine wave	—	-76	—	dBc
		200 kHz sine wave	—	-75	—	
		500 kHz sine wave	—	-75	—	
		1 MHz sine wave	—	-75	—	
Spurs Induced by External Power Supply Noise 50 mV <sub>PP</sub> Ripple LVDS 156.25 MHz Output V <sub>DD</sub> = 2.5 or 3.3 V	PSRR	100 kHz sine wave	—	-83	—	dBc
		200 kHz sine wave	—	-83	—	
		500 kHz sine wave	—	-83	—	
		1 MHz sine wave	—	-82	—	

**Notes:**

1. Applies to output frequency: 50, 100, 156.25, 212.5, 350 MHz.
2. Guaranteed by characterization. Jitter inclusive of any spurs.

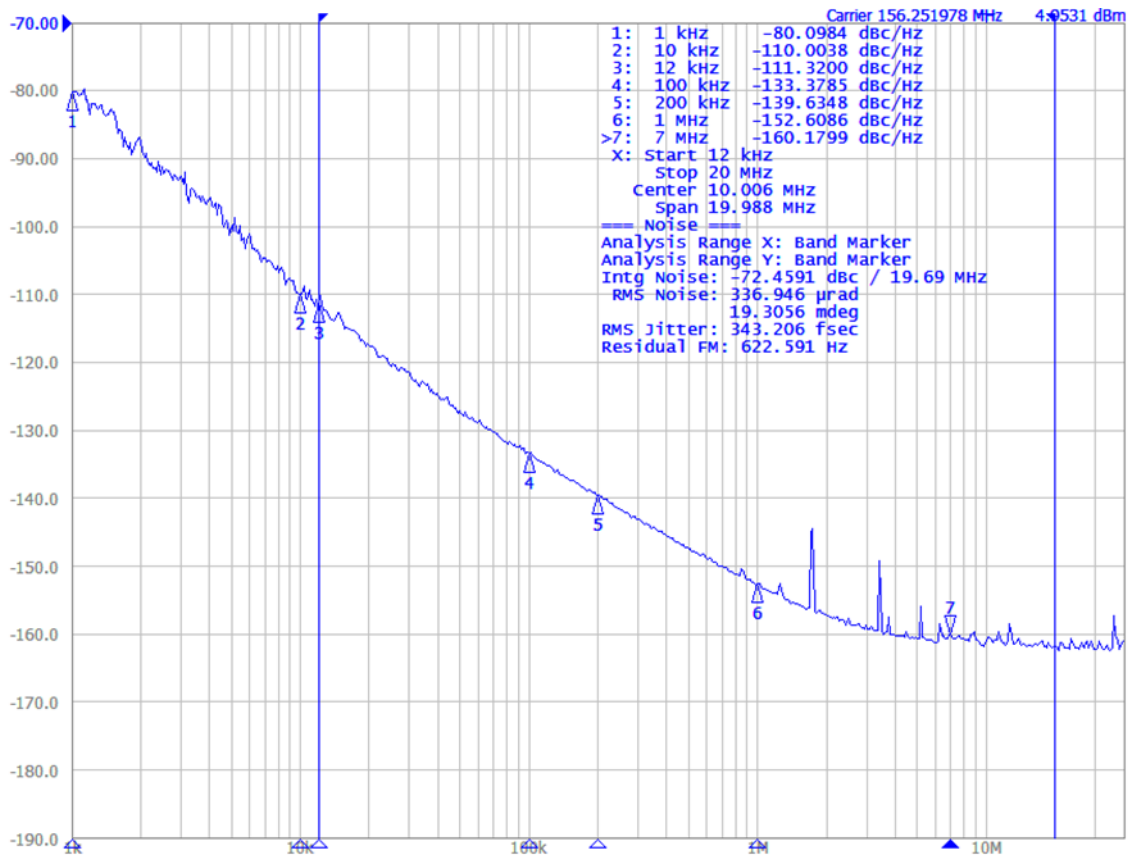


Figure 2.1. Phase Noise at 156.25 MHz

**Table 2.3. PCI-Express Clock Outputs (100 MHz HCSL)**

VDD = 1.8 V, 2.5 or 3.3 V ± 5%, TA = -40 to 105 °C

Parameter	Test Condition	Specification	Max	Units
PCIe Gen 1.1	Includes PLL BW 1.5 - 22 MHz Peaking = 3dB, T <sub>D</sub> =10 ns	N/A	0.311	ps
PCIe Gen 2.1	Includes PLL BW 5MHz & 8 - 16 MHz Peaking = 0.01 - 1 dB & 3 dB, T <sub>D</sub> =12ns Low Band, F < 1.5 MHz	3.1	0.022	ps
	Includes PLL BW 5MHz & 8 - 16 MHz Peaking = 0.01 - 1 dB & 3 dB, T <sub>D</sub> =12ns High Band, 1.5 MHz < F < Nyquist	3.0	0.259	ps
PCIe Gen 3.0 Common Clock	Includes PLL BW 2 - 4 MHz & 5 MHz Peaking = 0.01 - 2dB & 1dB, T <sub>D</sub> =12 ns CDR = 10 MHz	1	0.085	ps
PCIe Gen 4.0 Common Clock	Includes PLL BW 2 - 4 MHz & 5 MHz Peaking = 0.01 - 2dB & 1dB, T <sub>D</sub> =12 ns CDR = 10 MHz	0.5	0.085	ps
PCIe Gen 5.0 Common Clock	Includes PLL BW 500 kHz - 1.8 MHz Peaking = 0.01 - 2dB, T <sub>D</sub> =12 ns CDR = 20 MHz	0.15	0.033	ps
PCIe Gen 6.0 Common Clock	Includes PLL BW 500 kHz - 1 MHz Peaking = 0.01 - 2dB, T <sub>D</sub> =12 ns CDR = 10 MHz	0.1	0.021	ps

Class	Data Rate	Architecture	Specs	Max HF RMS	Max LF RMS	Max Pk-Pk	Compliance Summary
GEN1	2.5 Gb/s	Common Clock	1.1 2.1 3.1	310.77 fs	41.59 fs	N/A	N/A
GEN2	5 Gb/s	Common Clock	1.1 2.1 3.1	259.42 fs	21.89 fs	N/A	All PASS
GEN3	8 Gb/s	Common Clock	3.1 4.0	84.54 fs	4.68 fs	N/A	All PASS
GEN4	16 Gb/s	Common Clock	4.0	84.54 fs	4.68 fs	N/A	All PASS
GEN5	32 Gb/s	Common Clock	5.0	32.92 fs	2.09 fs	N/A	All PASS
GEN6	64 Gb/s	Common Clock	6.0	21.00 fs	0.88 fs	N/A	All PASS

**Figure 2.2. PCI-Express clock Compliance Summary**

**Table 2.4. Environmental Compliance and Package Information**

Parameter	Test Condition
Moisture Sensitivity Level	2

**Notes:**  
 For additional product information not listed in the data sheet (e.g. RoHS Certifications, MSDS data, qualification data, REACH Declarations, ECCN codes, etc.), contact [aeonsemi.com/contact\\_us](http://aeonsemi.com/contact_us)

**Table 2.5. Thermal Conditions**

Package	Parameter	Symbol	Test Condition	Value	Unit
5032 6-pin DFN	Thermal Resistance Junction to Ambient	$\Theta_{JA}$	Still Air	105	°C/W
	Thermal Resistance Junction to Board	$\Theta_{JB}$	Still Air	81	°C/W
	Max Junction Temperature	$T_J$	Still Air	125	°C
3225 6-pin DFN	Thermal Resistance Junction to Ambient	$\Theta_{JA}$	Still Air	108	°C/W
	Thermal Resistance Junction to Board	$\Theta_{JB}$	Still Air	84	°C/W
	Max Junction Temperature	$T_J$	Still Air	125	°C

**Table 2.6. Absolute Maximum Ratings<sup>1</sup>**

Parameter	Symbol	Rating	Unit
Maximum Operating Temp	$T_{AMAX}$	105	°C
Storage Temperature	$T_S$	-55 to 105	°C
Supply Voltage	$V_{DD}$	-0.5 to 3.8	V
Input Voltage	$V_{IN}$	-0.5 to $V_{DD} + 0.3$	V
ESD HBM (JESD22-A114)	HBM	4.0	kV
ESD CDM (JESD22-C101)	CDM	1.0	kV
Solder Temperature <sup>2</sup>	$T_{PEAK}$	260	°C
Solder Time at $T_{PEAK}$ <sup>2</sup>	$T_P$	20 - 40	sec

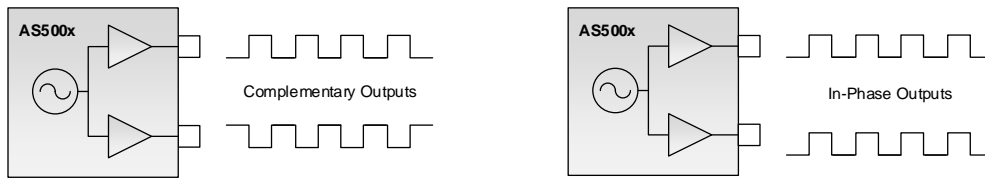
**Notes:**

1. Stresses beyond those listed in this table may cause permanent damage to the device. Functional operation specification compliance is not implied at these conditions. Exposure to maximum rating conditions for extended periods may affect device reliability.

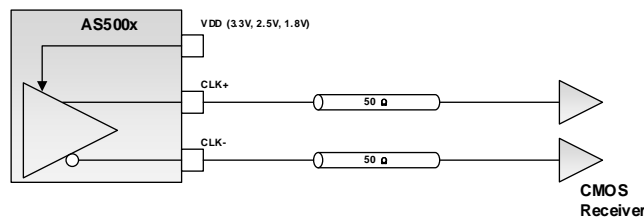
2. The device is compliant with JEDEC J-STD-020.

### 3. CMOS Buffer and Output Terminations

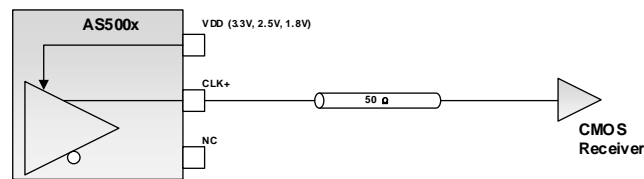
Dual CMOS output format ordering options support either complementary or in-phase signals for two identical frequency outputs. This feature enables replacement of multiple XOs with a single AS5001 device.



**Figure 3.1. Integrated 1:2 CMOS Buffer Supports In-Phase or Complementary Outputs**



**Figure 3.2. Dual CMOS termination**

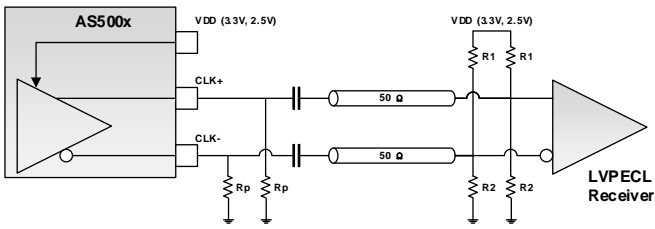


**Figure 3.3. Single CMOS termination**

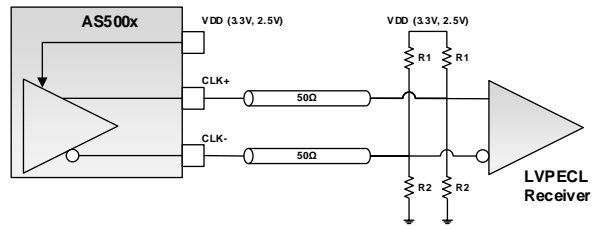


### 4. Recommended Output Terminations

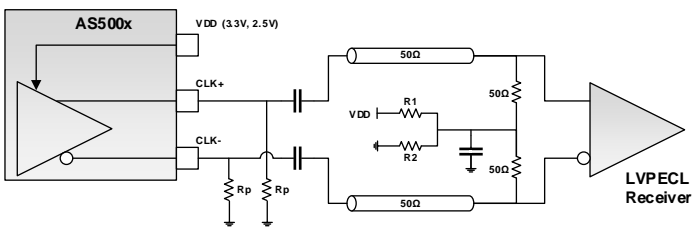
The output drivers support AC-coupled or DC-coupled terminations as shown in figures below.



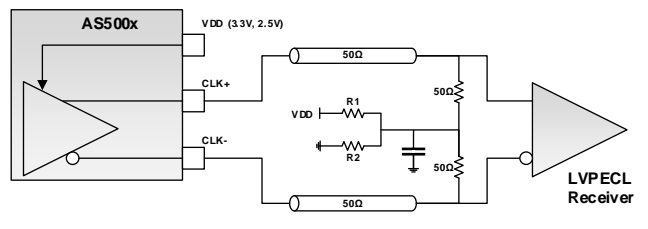
AC-Coupled LVPECL - Thevenin Termination



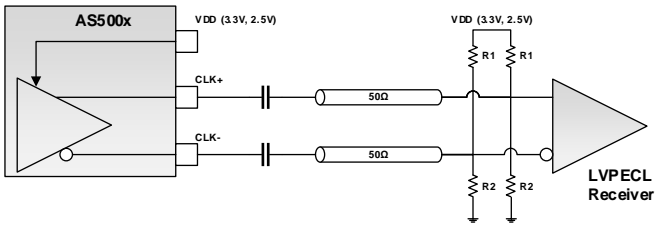
DC-Coupled LVPECL - Thevenin Termination



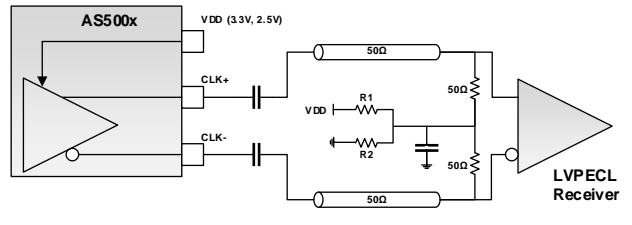
AC-Coupled LVPECL - 50  $\Omega$  w/VTT Bias



DC-Coupled LVPECL - 50  $\Omega$  w/VTT Bias



AC-Coupled Self-Biased LVEPCL - Thevenin Termination



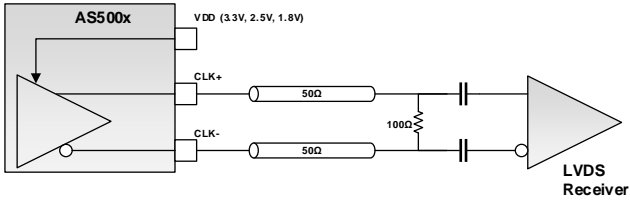
AC-Coupled Self-Biased LVEPCL - 50  $\Omega$  w/VTT Bias

Figure 4.1. LVPECL Output Terminations

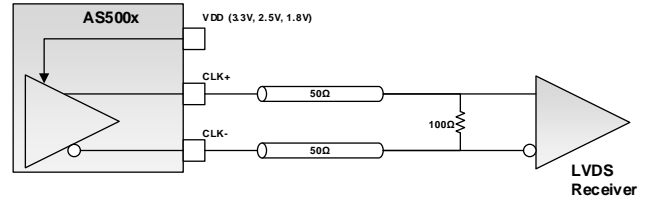
Table 4.1. LVPECL Termination Resistor Values

AC Coupled LVPECL Termination Resistor Values			
V <sub>DD</sub>	R <sub>p</sub>	R <sub>1</sub>	R <sub>2</sub>
3.3 V	158 $\Omega$	127 $\Omega$	82.5 $\Omega$
2.5 V	92 $\Omega$	250 $\Omega$	62.5 $\Omega$

DC Coupled LVPECL Termination Resistor Values		
V <sub>DD</sub>	R <sub>1</sub>	R <sub>2</sub>
3.3 V	127 $\Omega$	82.5 $\Omega$
2.5 V	250 $\Omega$	62.5 $\Omega$

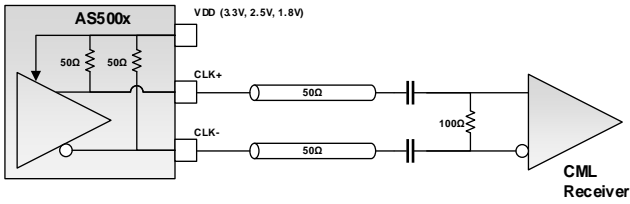


AC-Coupled LVDS

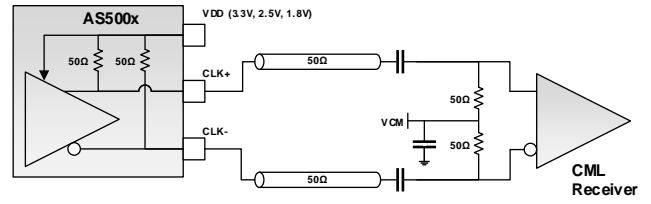


DC-Coupled LVDS

Figure 4.2. LVDS Output Termination

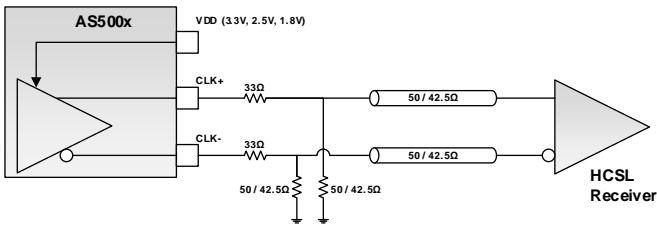


AC-Coupled CML without VCM

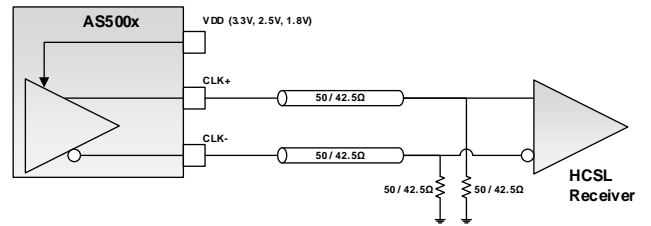


AC-Coupled CML with VCM

Figure 4.3. CML Output Termination



Source Terminated HCSL



Destination Terminated HCSL

Figure 4.4. HCSL Output Termination

5. Package Outline

5.1. Package Outline (5032)

The figure below illustrates the package details for the AS5001 devices in 5032 package. The table below lists the values for the dimensions shown in the illustration.

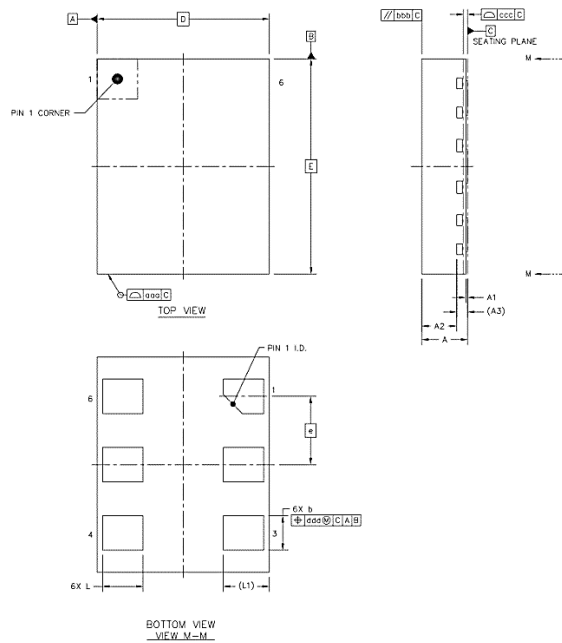


Figure 5.1. AS5001 5032 Package Outline Diagram

Table 5.1. Package Diagram Dimensions (mm)

Dimension	Min	Nom	Max
A	0.8	0.85	0.9
A1	0	0.035	0.05
A2	---	0.65	---
A3	0.203 REF		
b	0.59	0.64	0.69
D	3.2 BSC		
E	4 BSC		
e	1.27 BSC		
L	0.7	0.75	0.8
L1	0.85 REF		
aaa	0.1		
bbb	0.1		
ccc	0.08		
ddd	0.1		

Notes:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

## 5.2. Package Outline (3225)

The figure below illustrates the package details for the AS5001 devices in 3225 package. The table below lists the values for the dimensions shown in the illustration.

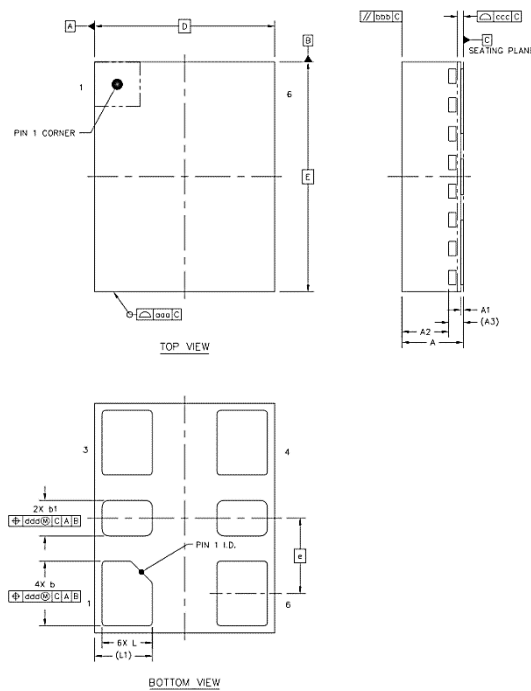


Figure 5.2. AS5001 3225 Package Outline Diagram

Table 5.2. Package Diagram Dimensions (mm)

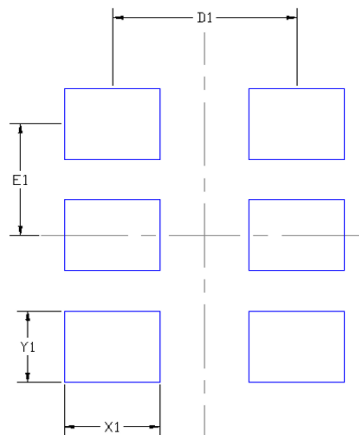
Dimension	Min	Nom	Max
A	0.8	0.85	0.9
A1	0	0.035	0.05
A2	---	0.65	---
A3	0.203 REF		
b	0.85	0.9	0.95
b1	0.45	0.5	0.55
D	2.5 BSC		
E	3.2 BSC		
e	1.05 BSC		
L	0.65	0.7	0.75
L1	0.8 REF		
aaa	0.1		
bbb	0.1		
ccc	0.08		
ddd	0.1		

**Notes:**

1. The dimensions in parentheses are reference.
2. All dimensions in millimeters (mm).
3. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

## 6. PCB Land Pattern (5032 and 3225 package)

The figure below illustrates the PCB land pattern for the AS5001. The table below lists the values for the dimensions shown in the illustration.



**Figure 6.1. AS5001 (5032 and 3225 package) PCB Land Pattern**

**Table 6.1. PCB Land Pattern Dimensions (mm)**

Dimension	Description	5032 Package Value (mm)	3225 Package Value (mm)
X1	Width - leads on long sides	0.7	0.75
Y1	Height - leads on long sides	0.9, 0.5	0.64
D1	Pitch in X directions of XLY1 leads	1.6	2.25
E1	Lead pitch XLY1 leads	1.05	1.27

### Notes:

The following notes and stencil design are shared as recommendations only. A customer or user may find it necessary to use different parameters and fine-tune their SMT process as required for their application and tooling.

### General

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
3. This Land Pattern Design is based on the IPC-7351 guidelines.
4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

### Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60  $\mu$ m minimum, all the way around the pad.

### Stencil Design

1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
2. The stencil thickness should be 0.125 mm (5 mils).
3. The ratio of stencil aperture to land pad size should be 0.8:1 for the pads.

### Card Assembly

1. A No-Clean, Type-3 solder paste is recommended.
2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

## 7. Top Marking (5032 and 3225 Package)

The figure below illustrates the mark specification for the AS5001. The table below lists the line information.

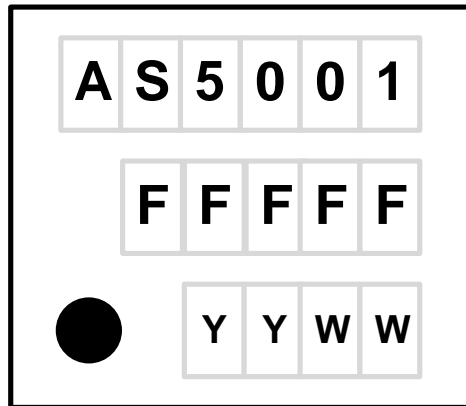


Figure 7.1. AS5001 Top Mark

Table 7.1. AS5001 Top Mark Description

Line	Position	Description
1	1-6	Device Name
2	1-5	Unique 5-digit Device Configuration Number
3	Position 1	Pin 1 orientation mark (dot)
	Position 2-3	Year (last two digits of the year), to be assigned by assembly site (ex: 2017 = 17)
	Position 4-5	Calendar Work Week number (1-53), to be assigned by assembly site

## 8. IMPORTANT NOTICE AND DISCLAIMER

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## 9. Revision History

Rev	Date	Description
1.00	Sep 2021	With certain specification update
0.95	Jun 2021	Corrected the Ordering Guide Insert -40~105oC temperature range option Insert section "PCIe clock compliance" Insert section "IMPORTANT NOTICE AND DISCLAIMER"
0.94	Mar 2021	Updated the Ordering Guide
0.93	Feb 2021	Corrected the Top Mark Corrected the storage temperature
0.92	Feb 2021	Corrected the PCB Land Pattern description Corrected the Top Mark description Updated the Ordering Guide
0.91	Oct 2020	Removed Note 3 "IEEE802.3-2005 10GbE jitter mask." Corrected figure # of section 3 and section
0.90	Sep 2020	Initial release